



**ELECTRONIC COPY**

LG799666385  
Report verification at igi.org



May 12, 2026

IGI Report Number **LG799666385**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **OVAL BRILLIANT**

Measurements **8.60 X 6.14 X 3.64 MM**

**GRADING RESULTS**

Carat Weight **1.22 CARAT**

Color Grade **D**

Clarity Grade **VVS 1**

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**GRADING RESULTS**

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**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **EXCELLENT**

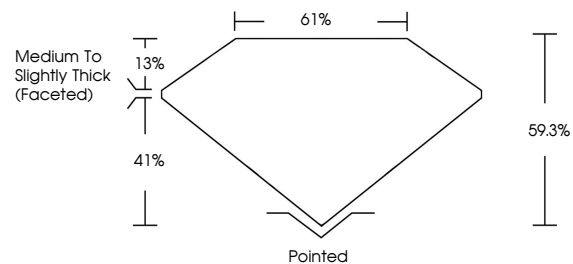
Fluorescence **NONE**

Inscription(s) **IGI LG799666385**

Comments: As Grown - No indication of post-growth treatment.

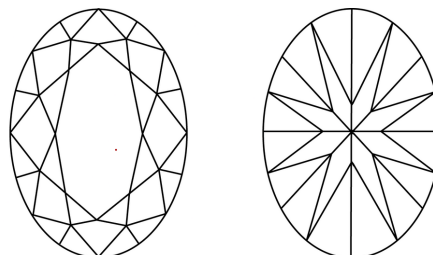
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

**PROPORTIONS**



Sample Image Used

**CLARITY CHARACTERISTICS**



**KEY TO SYMBOLS**

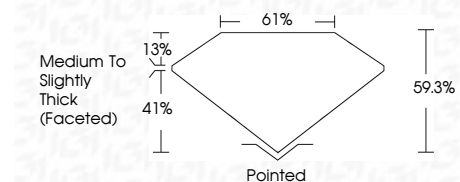
Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.

**COLOR**

D E F G H I J Faint Very Light Light

**CLARITY**

FL	IF	VVS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	I <sup>1-3</sup>
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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**IGI**



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**OVAL BRILLIANT**  
8.60 X 6.14 X 3.64 MM  
1.22 CARAT  
D  
VVS 1  
60%  
61%  
Medium to Slightly Thick (Faceted)  
Pointed  
EXCELLENT  
EXCELLENT  
NONE  
IGI LG799666385

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